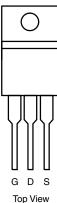


**Vishay Siliconix** 

## N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (Ω)</b>	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
30	0.0051 at V <sub>GS</sub> = 10 V	50 <sup>d</sup>	21.7		
30	0.0063 at $V_{GS}$ = 4.5 V	50 <sup>d</sup>	21.7		





SUP50N03-5m1P-GE3 (Lead (Pb)-free and Halogen-free)

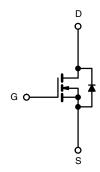
**Ordering Information:** 

#### **FEATURES**

- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested
- Material categorization: ٠ For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Power Supply
  - Secondary Synchronous Rectification
- DC/DC Converter



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T <sub>C</sub> = 25 °C, unless ot	herwise noted)			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	30	v	
Gate-Source Voltage	Gate-Source Voltage		± 20	v	
Continuous Drain Current ( $T_1 = 150 \ ^{\circ}C$ )	T <sub>C</sub> = 25 °C	1-	50 <sup>d</sup>		
Continuous Drain Current $(T_j = 150^{\circ} C_j)$	T <sub>C</sub> = 70 °C	I <sub>D</sub>	50 <sup>d</sup>	A	
Pulsed Drain Current		I <sub>DM</sub>	100	A	
Avalanche Current		I <sub>AS</sub>	40		
Single Avalanche Energy <sup>a</sup>	L = 0.1 mH	E <sub>AS</sub>	80	mJ	
	T <sub>C</sub> = 25 °C	Р	59.5 <sup>b</sup>	14/	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C <sup>c</sup>		2.7	W	
Operating Junction and Storage Temperature Ra	inge	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) <sup>c</sup>	R <sub>thJA</sub>	46	°C/W		
Junction-to-Case (Drain)	R <sub>thJC</sub>	2.1	0/11		

Notes:

a. Duty cycle  $\leq$  1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

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## SUP50N03-5m1P

### Vishay Siliconix



<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static			•			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{DS} = 0 V, I_{D} = 250 \mu A$	30			V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		2.5	v
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 30$ V, $V_{GS} = 0$ V, $T_{J} = 125$ °C			50	μΑ
		$V_{DS} = 30$ V, $V_{GS} = 0$ V, $T_{J} = 150$ °C			250	1
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10$ V, $V_{GS} = 10$ V	50			Α
	Р	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 22 \text{ A}$		0.0042	0.0051	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0052	0.0063	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		110		S
Dynamic <sup>b</sup>						
Input Capacitance	C <sub>iss</sub>			2780		pF
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$ , $V_{DS} = 15 V$ , f = 1 MHz		641		
Reverse Transfer Capacitance	C <sub>rss</sub>			260		
Tatal Cata Channel	Q <sub>g</sub> -	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		44	66	
Total Gate Charge <sup>c</sup>				21.7	32.6	nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		7		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			6.7		
Gate Resistance	Rg	f = 1 MHz	0.7	3.5	7	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			8	16	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 15 \text{ V}, \text{ R}_{1} = 1.5 \Omega$		9	18	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		35	53	ns
Fall Time <sup>c</sup>	t <sub>f</sub>			9	18	
Drain-Source Body Diode Ratings a	nd Characteris	stics T <sub>C</sub> = 25 °C <sup>b</sup>	•	•		
Continuous Current	۱ <sub>S</sub>				50	٨
Pulsed Current	I <sub>SM</sub>				100	A
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{F} = 10 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.5	V
Reverse Recovery Time	t <sub>rr</sub>			34	51	ns
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	I <sub>F</sub> = 10 A, dl/dt = 100 A/μs		2	3	Α
Reverse Recovery Charge	Q <sub>rr</sub>			34	51	nC

Notes:

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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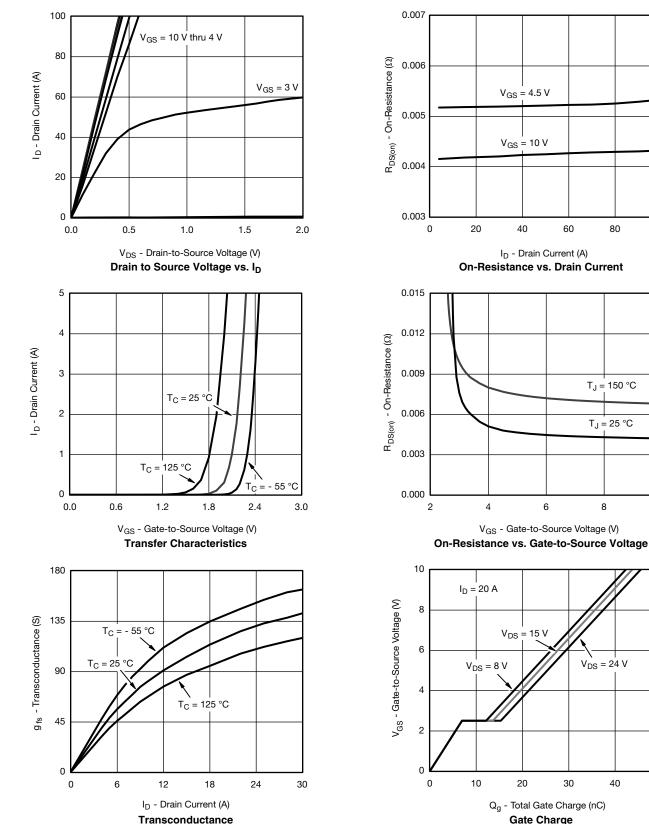
## SUP50N03-5m1P

80

100

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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

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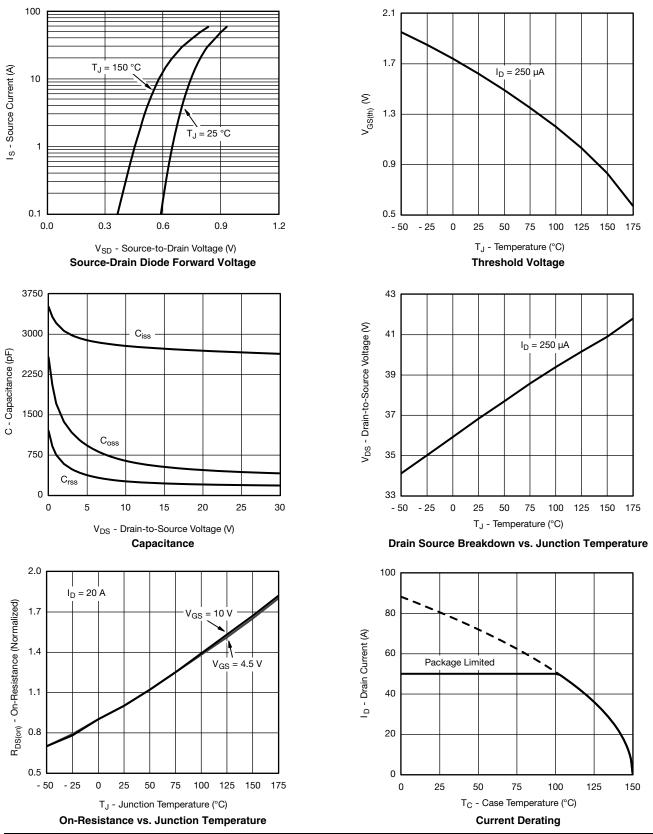
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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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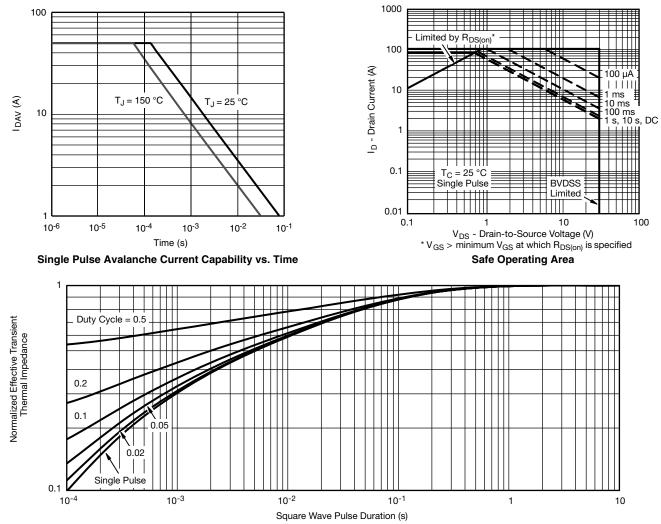
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## SUP50N03-5m1P

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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg266570">www.vishay.com/ppg266570</a>.



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### **TO-220AB**



	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
E	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
	0413-Rev. P,		0.102	0.118

Note

 $^{\star}$  M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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